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#### NPN SILICON POWER SWITCHING TRANSISTORS

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TO-39 Metal Can Package

BC140, BC141

# Medium Power Amplifier and Switching Applications Complementary BC160 and BC161

#### **ABSOLUTE MAXIMUM RATINGS**

DESCRIPTION	SYMBOL	BC140	BC141	UNITS
Collector Emitter Voltage	V <sub>CEO</sub>	40	60	V
Collector Base Voltage	V <sub>CBO</sub>	80	100	V
Emitter Base Voltage	$V_{EBO}$		7.0	V
Collector Current - Continuous	I <sub>C</sub>		A	
Power Dissipation@ T <sub>a</sub> =25°C	P <sub>D</sub>		W	
Derate Above 25°C			mW/ ºC	
Power Dissipation@ T <sub>c</sub> =25°C	$P_{D}$	4.0		W
Derate Above 25°C			mW/ ºC	
Operating and Storage Junction Temperature Range	$T_{j},T_{stg}$	- 6	°C	

#### THERMAL CHARACTERISTICS

Junction to Ambient in free air	$R_{th(j-a)}$	219	°C/W
Junction to Case	$R_{th(i-c)}$	44	°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Emitter Voltage	V <sub>CES</sub>	$I_{C}=100\mu A, V_{BE}=0$				
		BC140	80			V
		BC141	100			V
Collector Emitter Voltage	*V <sub>CEO</sub>	$I_C=30\text{mA}, I_B=0$				
		BC140	40			V
		BC141	60			V
Emitter Base Voltage	$V_{EBO}$	$I_{E}=100\mu A, I_{C}=0$	7			V
Collector Cut off Current	I <sub>CES</sub>	$V_{CE}$ =60V, $V_{BE}$ =0			100	nA
		V <sub>CE</sub> =60V, V <sub>BE</sub> =0, T <sub>a</sub> =150°C			100	μΑ
DC Current Gain	*h <sub>FE</sub>	I <sub>C</sub> =100mA, V <sub>CE</sub> =1V				
		BC140 / BC141	40		400	
		Group-6	40		100	
		Group-10	63		160	
		Group-16	100		250	
		I <sub>C</sub> =1A, V <sub>CE</sub> =1V				
		BC140 / BC141		26		
		Group-6		15		
		Group-10		20		
		Group-16		30		

<sup>\*</sup>Pulsed: Pulse duration <300ms, Duty cycle < 1%

BC140, BC141



TO-39 Metal Can Package

#### ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Emitter Saturation Voltage	*V <sub>CE (sat)</sub>	$I_{C}=1A, I_{B}=0.1A$			1.0	<b>V</b>
Base Emitter on Voltage	*V <sub>BE (on)</sub>	I <sub>C</sub> =1A, V <sub>CE</sub> =1V			2.0	V

#### **DYNAMIC CHARACTERISTICS**

Transition Frequency	f <sub>T</sub>	$I_C$ =50mA, $V_{CE}$ =10V, f=20MHz	50		MHz
Output Capacitance	C <sub>ob</sub>	$V_{CB}$ =10V, $I_E$ =0, f=1MHz		25	рF
Input Capacitance	$C_{ib}$	$V_{EB}$ =0.5V, $I_{C}$ =0, f=1MHz		80	рF

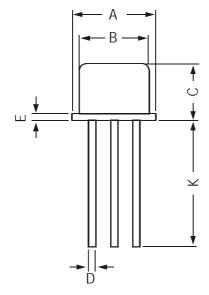
#### **SWITCHING CHARACTERISTICS**

Turn on time	t <sub>on</sub>	I <sub>C</sub> =150mA, I <sub>B1</sub> =7.5mA		250	ns
Turn off time	t <sub>off</sub>	$I_{C}$ =150mA, $I_{B1}$ = $I_{B2}$ =7.5mA		850	ns

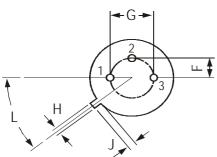
<sup>\*</sup>Pulsed: Pulse duration <300ms, Duty cycle < 1%

## **TO-39 Metal Can Package**

### **TO-39 Metal Can Package**



DIM	MIN	MAX					
Α	8.50	9.39					
В	7.74	8.50					
С	6.09	6.60					
D	0.40	0.53					
E		0.88					
F	2.41	2.66					
G	4.82	5.33					
Н	0.71	0.86					
J	0.73	1.02					
Κ	12.70	_					
L	42 DEG	48 DEG					





All dimensions are in mm

PIN CONFIGURATION

- 1. EMITTER
- 2. BASE 3. COLLECTOR

## **Packing Details**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight ∕Qty	Size	Qty	Size Oty Gr Wt		
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Notes BC140, BC141

TO-39 Metal Can Package

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